

APPLICATION DATA SHEET

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Correspondence Information

Correspondence Customer Number:: 6449

Application Information

Title Line One:: HIGH VOLTAGE SEMICONDUCTOR DEVICE HAVING
Title Line Two:: HIGH BREAKDOWN VOLTAGE AND METHOD OF
Title Line Three:: FABRICATING THE SAME
Total Drawing Sheets:: 7
Formal Drawings?: Yes
Application Type:: Utility
Docket Number:: 1751-294.Con

Secrecy Order in Parent Appl?:

Representative Information

Representative Customer Number:: 6449

Continuity Information

This application is a:: Continuation of
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Prior Foreign Applications

Foreign Application One:: Korean Patent Application No. 2001-2166
Filing Date:: January 15, 2001
Country:: Korea
Priority Claimed:: Yes

51 **Assignment Information**

52
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